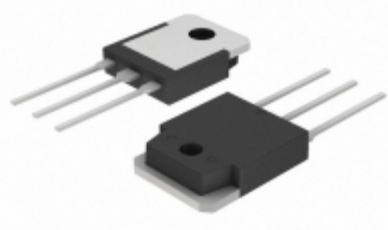



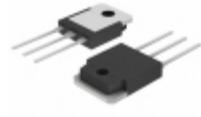
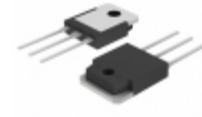


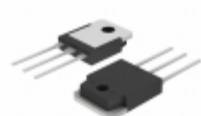


	<h2 style="color: red;">FQA13N50</h2>	
	Hersteller-Teilenummer:	FQA13N50
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 500V 13.4A TO-3P
	Datenblätter:	 FQA13N50.pdf
	RoHs Status:	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	Lagerzustand:	New original, 875 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	FQA13N50
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 500V 13.4A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	875 pcs Stock
detaillierte Beschreibung	N-Channel 500V 13.4A (Tc) 190W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	190W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	13.4A (Tc)
Rds On (Max) @ Id, Vgs	430 mOhm @ 6.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2300pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)













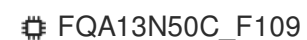























FQA13N50 ist neu im Original, Suche FQA13N50 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA13N50 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQA13N50: Info@Y-IC.com

Sie können auch interessiert sein:

 FQA13N50C Fairchild/ON Semiconductor MOSFET N-CH 500V 13.5A TO-3P	 FQA12N60 AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 12A TO-3P	 FQA12P20 AMI Semiconductor / ON Semiconductor MOSFET P-CH 200V 12.6A TO-3P	 FQA13N50CF Fairchild/ON Semiconductor MOSFET N-CH 500V 15A TO-3P
 FQA13N50C AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13.5A TO-3P	 FQA13N50CF AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 15A TO-3P	 FQA12P20 Fairchild/ON Semiconductor MOSFET P-CH 200V 12.6A TO-3P	 FQA13N50C-F109 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 13.5A

heiße Teile

Mehr

 FQA10N60C	 FQA10N60C	 FQA10N80C	 FQA10N80C	 FQA10N80C_F109
 FQA11N90	 FQA11N90	 FQA11N90C	 FQA11N90C	 FQA11N90C
 FQA11N90C_F109	 FQA11N90_F109	 FQA12N60C	 FQA12P20	 FQA12P20
 FQA13N50	 FQA13N50C	 FQA13N50C	 FQA13N50C_F109	 FQA13N80
 FQA13N80	 FQA13N80_F109	 FQA140N10	 FQA140N10	 FQA14N30
 FQA14N30	 FQA160N08	 FQA160N08	 FQA16N50	 FQA16N50
 FQA170N06	 FQA170N06	 FQA18N40	 FQA18N50	 FQA19N20C
 FQA19N20C	 FQA19N20L	 FQA19N20L	 FQA19N60	 FQA19N60
 FQA20N40	 FQA20N40	 FQA20N50	 FQA20N60	 FQA20N80
 FQA24N50	 FQA24N50	 FQA24N50F	 FQA24N50F	 FQA24N60

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited